NSN 5962-01-372-6630

Memory Microcircuit - Page 1 of 2



view Online at https://aerobasegroup.com/nsn/5962-01-372-6630
Body Length:
Between 1.040 inches and 1.060 inches
Body Width:
Between 0.290 inches and 0.310 inches
Body Height:
Between 0.180 inches and 0.200 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Eolorops
Features Provided:
Burn in, mil-std-883, class b and electrostatic sensitive and monolithic and programmed and tested to mil-std-883 and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed
Voltage Rating And Type Per Characteristic:
0.5 volts total supply and 7.0 volts total supply
Memory Device Type:
Pal
Special Features:
ESD;-CH-ECK-SUM0
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

N/a

20 printed circuit Shelf Life:

NSN 5962-01-372-6630

Memory Microcircuit - Page 2 of 2



			ure:	

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0